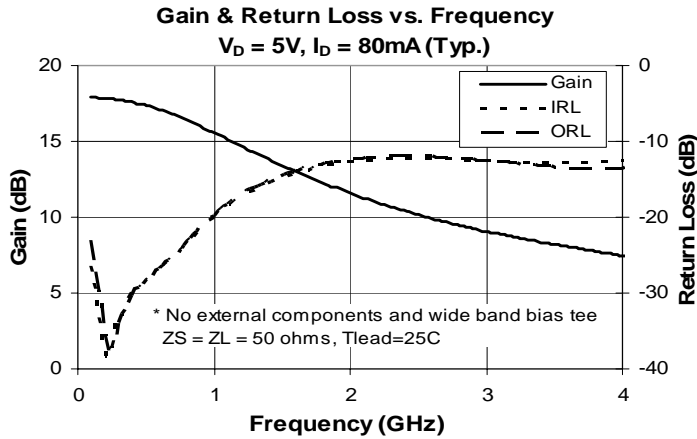




Product Description

Sirenza Microdevices' SGC-6386Z is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SGC-6386Z does not require a drop resistor as compared to typical Darlington amplifiers. The SGC-6386Z product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to 50 ohms.

The matte tin finish on Sirenza's lead-free "Z" package is applied using a post annealing process to mitigate tin whisker formation and is RoHS compliant per EU Directive 2002/95. The package body is manufactured with green molding compounds that contain no antimony trioxide or halogenated fire retardants.



Preliminary Information

SGC-6386Z



50-4000 MHz Silicon Germanium Cascadable Gain Block



Product Features

- Single Fixed 5V Supply
- Supply Drop Resistor not required
- Patented Self Bias Circuitry
- P1dB = 18.3 dBm at 1950 MHz
- IP3 = 34.3 dBm at 1950 MHz
- Robust 1000V ESD, Class 1C HBM

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Typical performance with appropriate application circuit

Symbol	Parameters	Units	Frequency	Min.	Typ.	Max.
G	Small Signal Gain	dB	850 MHz 1950 MHz		16.3 11.9	
P _{1dB}	Output Power at 1dB Compression	dBm	850 MHz 1950 MHz		19.3 18.3	
OIP ₃	Output Third Order Intercept Point	dBm	850 MHz 1950 MHz		35.6 34.3	
IRL	Input Return Loss	dB	1950 MHz		18.0	
ORL	Output Return Loss	dB	1950 MHz		17.0	
NF	Noise Figure	dB	1930 MHz		4.2	
V _D	Device Operating Voltage	V			5.0	
I _D	Device Operating Current	mA			80	
R _{th, j-l}	Thermal Resistance (junction to lead)	°C/W			106	

Test Conditions: $V_D = 5.0V$ $I_D = 80mA$ Typ. OIP₃ Tone Spacing = 1MHz $T_L = 25°C$
 $Z_S = Z_L = 50$ Ohms Pout per tone = 0 dBm

The information provided herein is believed to be reliable at press time. Sirenza Microdevices assumes no responsibility for inaccuracies or omissions. Sirenza Microdevices assumes no responsibility for the use of this information, and all such information shall be entirely at the user's own risk. Prices and specifications are subject to change without notice. No patent rights or licenses to any of the circuits described herein are implied or granted to any third party. Sirenza Microdevices does not authorize or warrant any Sirenza Microdevices product for use in life-support devices and/or systems. Copyright 2005 Sirenza Microdevices, Inc.. All worldwide rights reserved.



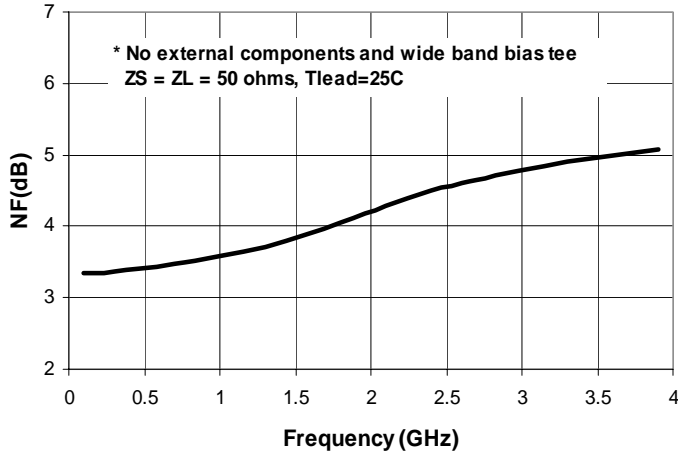
Preliminary Information
SGC-6386Z 0.05-4.0 GHz Cascadeable MMIC Amplifier

Typical RF Performance at Key Operating Frequencies (Application Circuit)

Symbol	Parameter	Unit	Frequency (MHz)					
			100 - 1000MHz App. Circuit			1000 - 2200MHz App. Circuit		
			100	500	850	1000	1950	2200
G	Small Signal Gain	dB	17.5	17.3	16.2	15.1	11.9	11.1
OIP ₃	Output Third Order Intercept Point	dBm	35.8	36.2	35.6	34.9	34.3	33.6
P _{1dB}	Output Power at 1dB Compression	dBm	19.4	19.7	19.3	18.9	18.3	18.0
IRL	Input Return Loss	dB	10.0	35.0	21.0	12.0	18.0	16.0
ORL	Output Return Loss	dB	12.0	20.0	22.0	15.0	17.0	15.0
S ₁₂	Reverse Isolation	dB	21.0	21.0	21.0	21.0	19.0	18.0
NF	Noise Figure	dB	3.1	3.3	3.4	3.5	4.2	4.3

Test Conditions: V_D = 5V I_D = 80mA Typ. OIP₃ Tone Spacing = 1MHz, Pout per tone = 0 dBm
 T_L = 25°C Z_S = Z_L = 50 Ohms

NF vs. Frequency (V_D = 5V, I_D = 80mA Typ.)



Absolute Maximum Ratings

Parameter	Absolute Limit
Max Device Current (I _{CE})	120 mA
Max Device Voltage (V _{CE})	6.5 V
Max. RF Input Power* (See Note)	+18 dBm
Max. Junction Temp. (T _J)	+150°C
Operating Temp. Range (T _L)	-40°C to +85°C
Max. Storage Temp.	+150°C

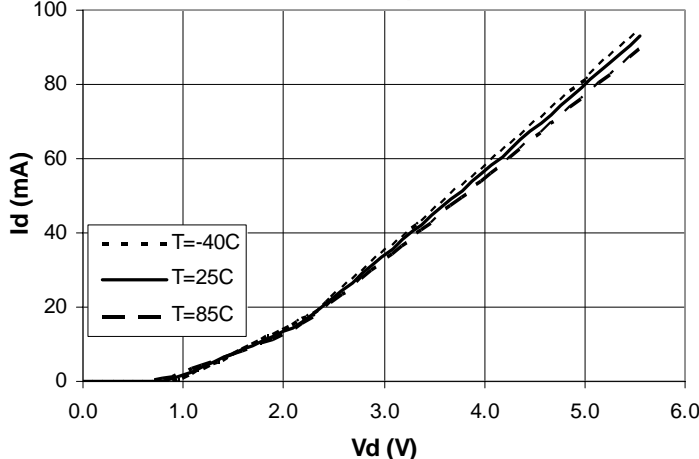
*Note: Load condition, Z_L = 50 Ohms

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH, j-l} \quad T_L = T_{LEAD}$$

I_d vs. V_d Vs. Temperature



Reliability & Qualification Information

Parameter	Rating
ESD Rating - Human Body Model (HBM)	Class 1C
Moisture Sensitivity Level	MSL 1

This product qualification report can be downloaded at
www.sirenza.com



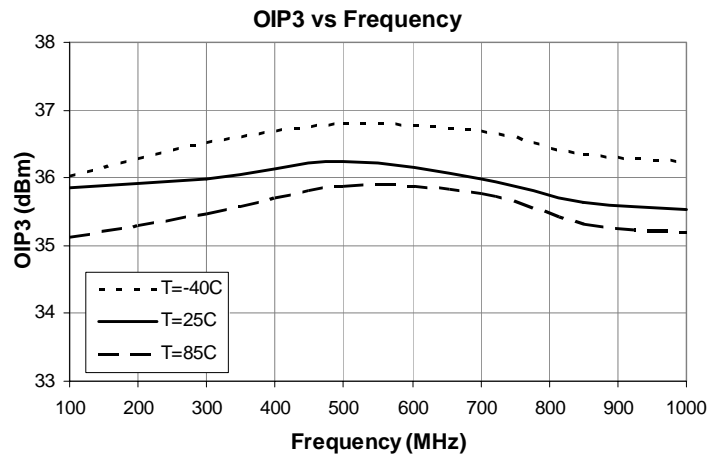
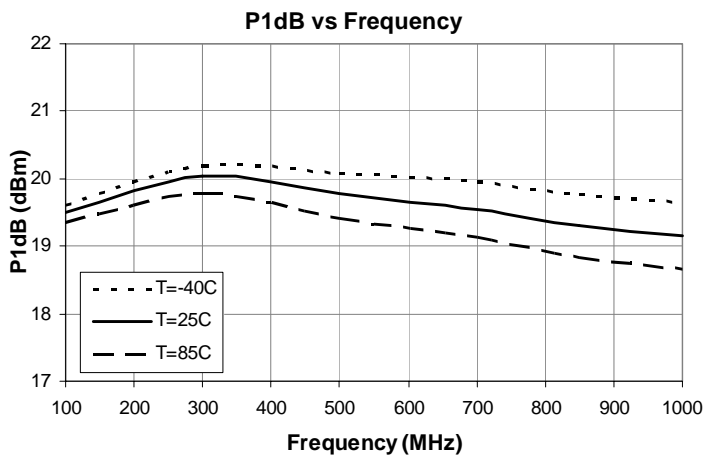
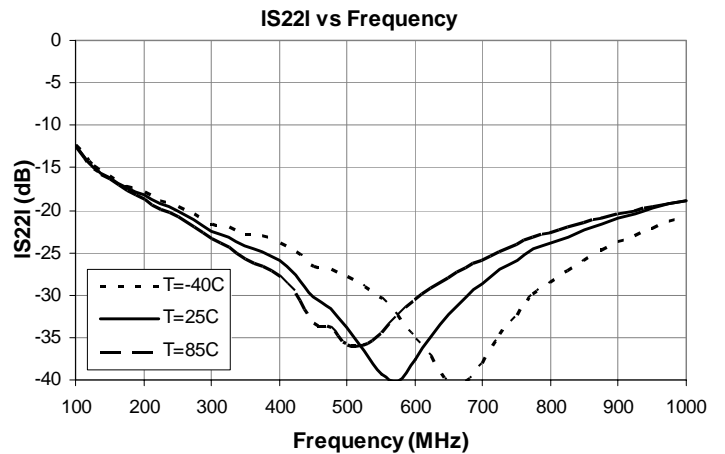
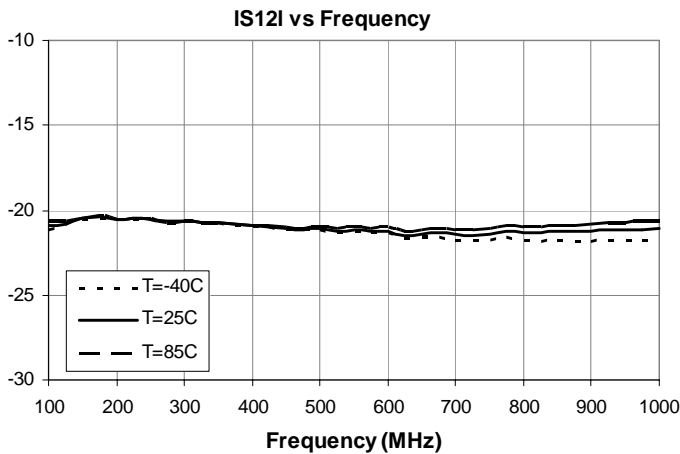
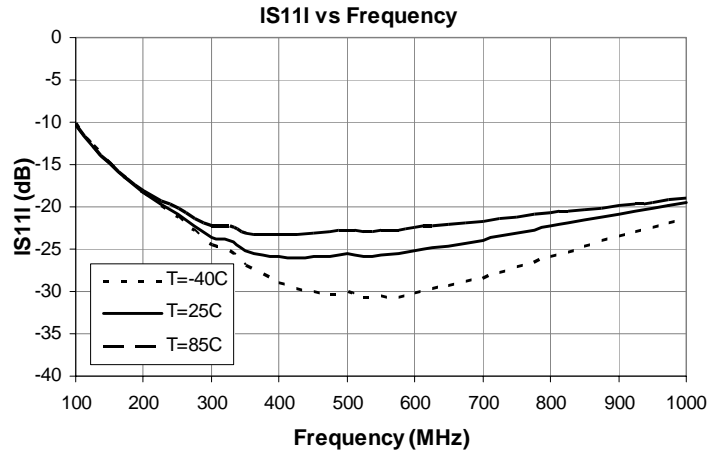
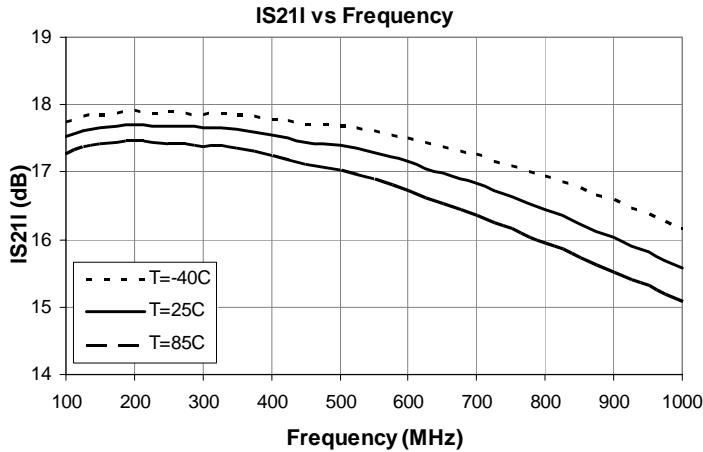
Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.



Preliminary Information
SGC-6386Z 0.05-4.0 GHz Cascadeable MMIC Amplifier

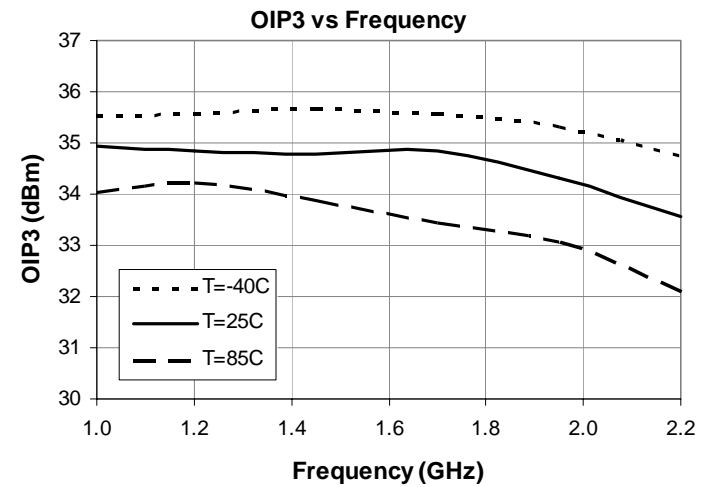
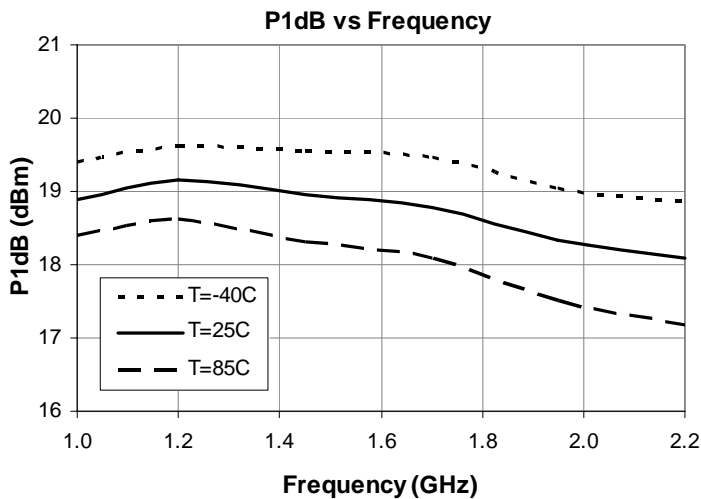
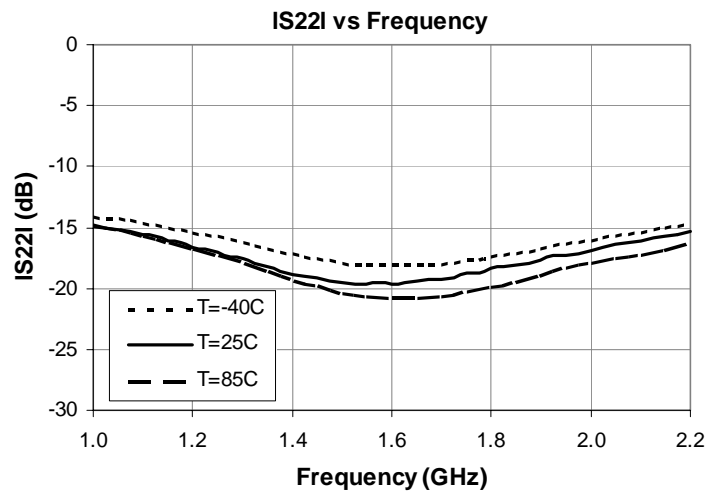
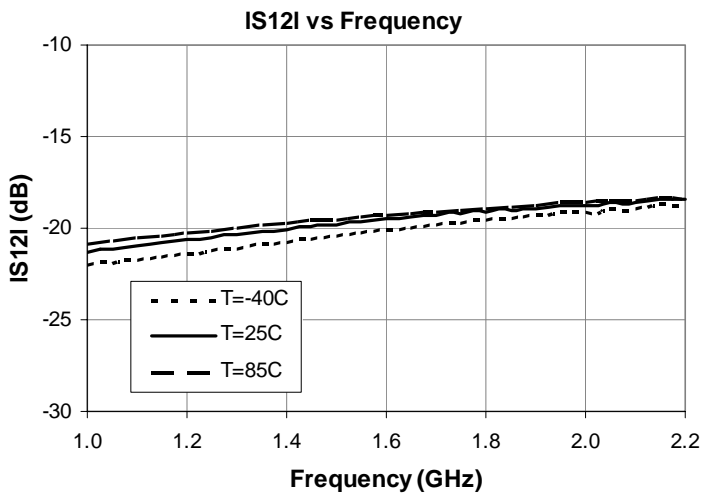
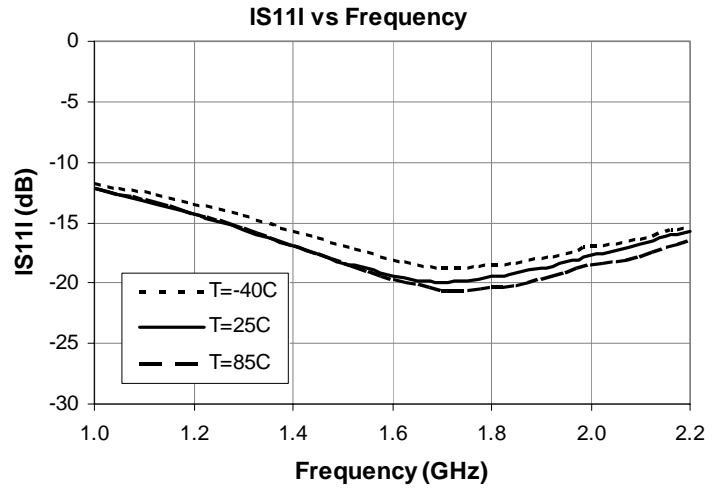
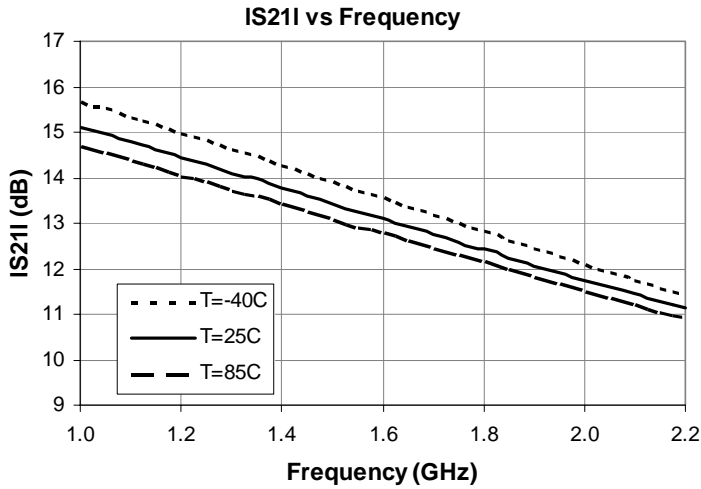
Typical RF Performance, 100-1000 MHz Application Circuit
 (Bias: $V_D = 5.0$ V, $I_D = 80$ mA (Typ.))

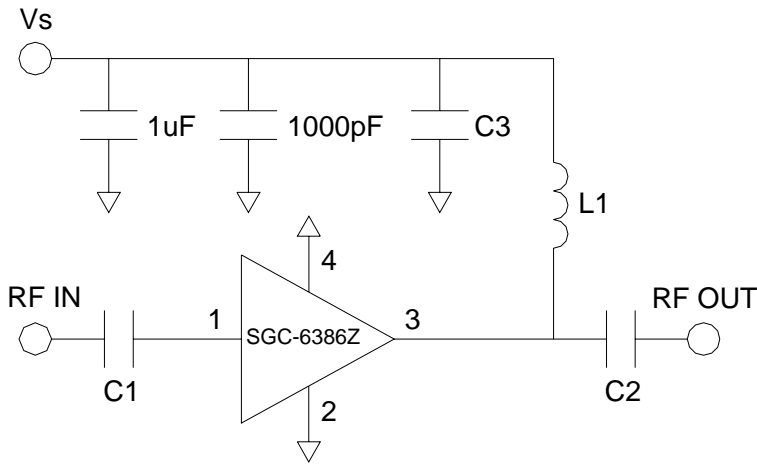




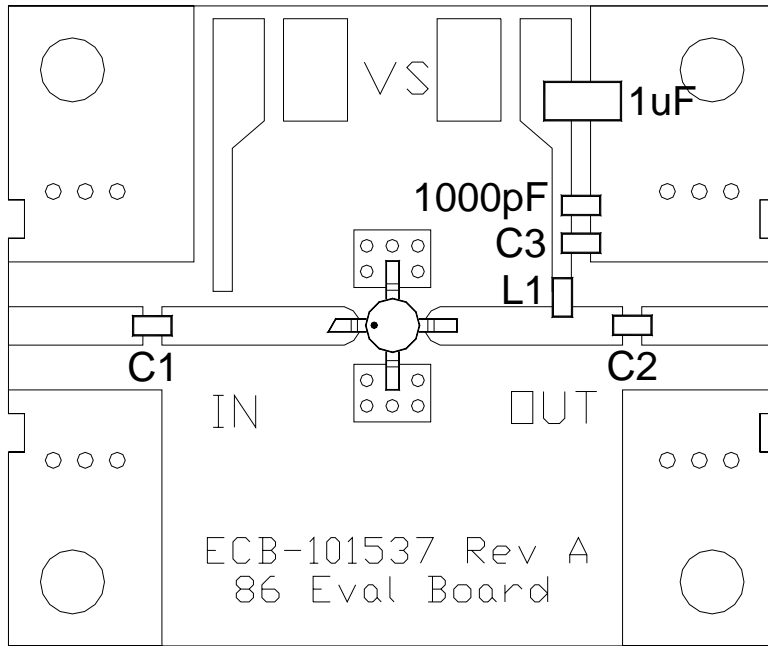
Preliminary Information
SGC-6386Z 0.05-4.0 GHz Cascadeable MMIC Amplifier

Typical RF Performance, 1000-2200 MHz Application Circuit
 (Bias: $V_D = 5.0$ V, $I_D = 80$ mA (Typ.))





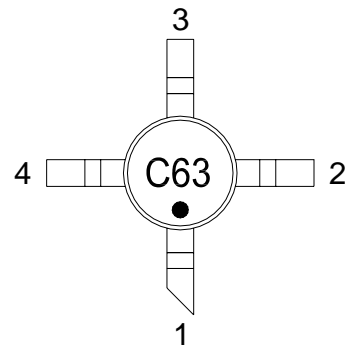
Application Circuit Element Values		
Reference Designator	100-1000MHz	1000-2200MHz
C1	1000pF	6.8pF
C2	100pF	6.8pF
C3	100pF	6.8pF
L1	100nH	39nH



Mounting Instructions

1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
2. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

Part Identification Marking & Pinout



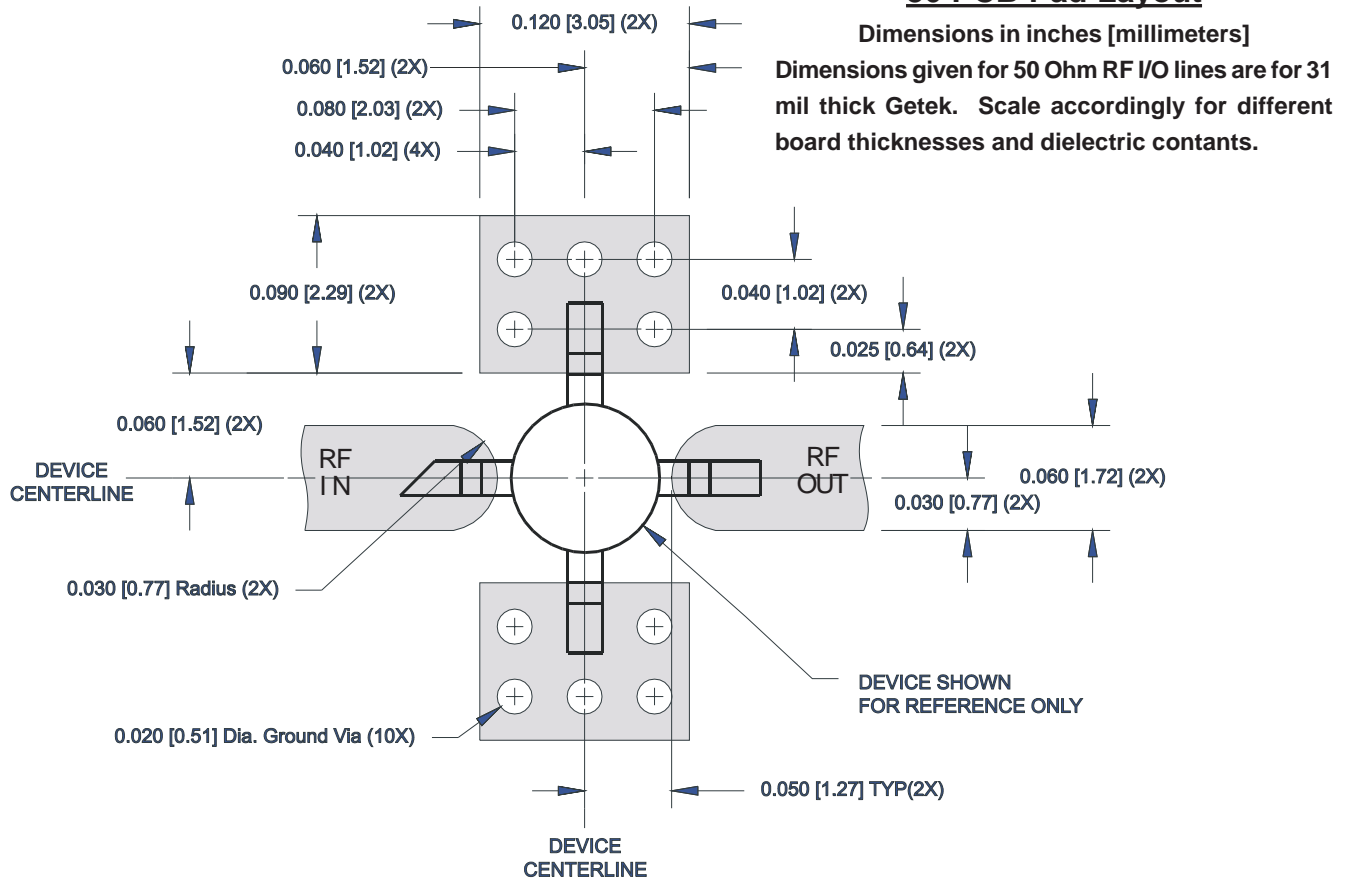
Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation
2,4	GND	Connection to ground. Use via holes as close to the device ground leads as possible to reduce ground inductance and achieve optimum RF performance
3	RF OUT / DCBIAS	RF output and bias pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.

Part Number	Package / Lead Composition	Reel Size	Devices / Reel
SGC-6386Z	Lead Free, RoHS Compliant	13"	3000



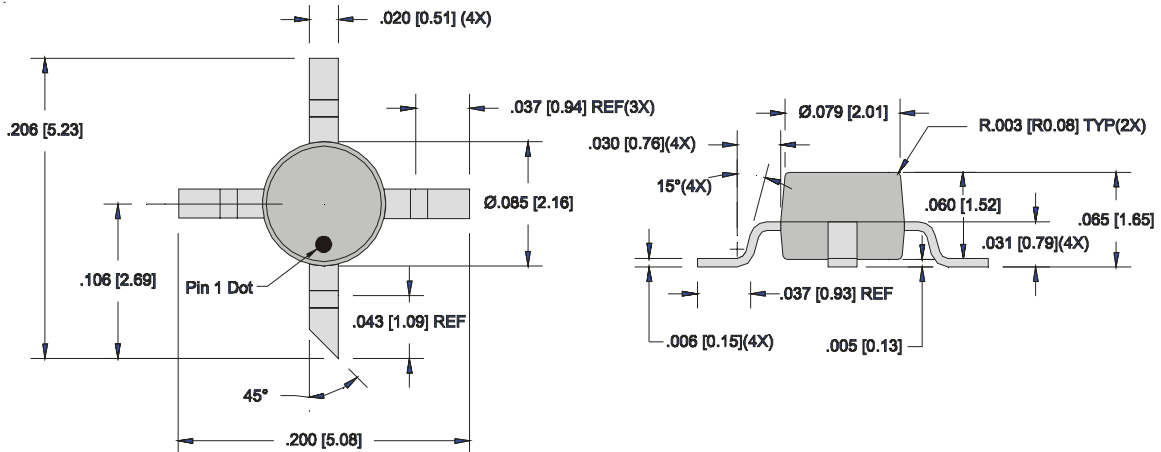
Preliminary Information
SGC-6386Z 0.05-4.0 GHz Cascadeable MMIC Amplifier

86 PCB Pad Layout



86 Nominal Package Dimensions

Dimensions in inches [millimeters]
 A link to the 86 package outline drawing with full dimensions and tolerances may be found on the product web page at www.sirenza.com.



SUNSTAR 商斯达实业集团是集研发、生产、工程、销售、代理经销、技术咨询、信息服务等为一体的高科技企业，是专业高科技电子产品生产厂家，是具有 10 多年历史的专业电子元器件供应商，是中国最早和最大的仓储式连锁规模经营大型综合电子零部件代理分销商之一，是一家专业代理和分销世界各大品牌 IC 芯片和电子元器件的连锁经营综合性国际公司，专业经营进口、国产名厂名牌电子元件，型号、种类齐全。在香港、北京、深圳、上海、西安、成都等全国主要电子市场设有直属分公司和产品展示展销窗口门市部专卖店及代理分销商，已在全国范围内建成强大统一的供货和代理分销网络。我们专业代理经销、开发生产电子元器件、集成电路、传感器、微波光电元器件、工控机/DOC/DOM 电子盘、专用电路、单片机开发、MCU/DSP/ARM/FPGA 软件硬件、二极管、三极管、模块等，是您可靠的一站式现货配套供应商、方案提供商、部件功能模块开发配套商。商斯达实业公司拥有庞大的资料库，有数位毕业于著名高校——有中国电子工业摇篮之称的西安电子科技大学（西军电）并长期从事国防尖端科技研究的高级工程师为您精挑细选、量身订做各种高科技电子元器件，并解决各种技术问题。

微波光电部专业代理经销高频、微波、光纤、光电元器件、组件、部件、模块、整机；电磁兼容元器件、材料、设备；微波 CAD、EDA 软件、开发测试仿真工具；微波、光纤仪器仪表。欢迎国外高科技微波、光纤厂商将优秀产品介绍到中国、共同开拓市场。长期大量现货专业批发高频、微波、卫星、光纤、电视、CATV 器件：晶振、VCO、连接器、PIN 开关、变容二极管、开关二极管、低噪晶体管、功率电阻及电容、放大器、功率管、MMIC、混频器、耦合器、功分器、振荡器、合成器、衰减器、滤波器、隔离器、环行器、移相器、调制解调器；光电子器件和组件：红外发射管、红外接收管、光电开关、光敏管、发光二极管和发光二极管组件、半导体激光二极管和激光器组件、光电探测器和光接收组件、光发射接收模块、光纤激光器和光放大器、光调制器、光开关、DWDM 用光发射和接收器件、用户接入系统光收发器件与模块、光纤连接器、光纤跳线/尾纤、光衰减器、光纤适配器、光隔离器、光耦合器、光环行器、光复用器/转换器；无线收发芯片和模组、蓝牙芯片和模组。

更多产品请看本公司产品专用销售网站：

商斯达中国传感器科技信息网：<http://www.sensor-ic.com/>

商斯达工控安防网：<http://www.pc-ps.net/>

商斯达电子元器件网：<http://www.sunstare.com/>

商斯达微波光电产品网：[HTTP://www.rfoe.net/](http://www.rfoe.net/)

商斯达消费电子产品网：<http://www.icasic.com/>

商斯达实业科技产品网：<http://www.sunstars.cn/> 微波元器件销售热线：

地址：深圳市福田区福华路福庆街鸿图大厦 1602 室

电话：0755-82884100 83397033 83396822 83398585

传真：0755-83376182 (0) 13823648918 MSN: SUNS8888@hotmail.com

邮编：518033 E-mail:szss20@163.com QQ: 195847376

深圳赛格展销部：深圳华强北路赛格电子市场 2583 号 电话：0755-83665529 25059422

技术支持：0755-83394033 13501568376

欢迎索取免费详细资料、设计指南和光盘；产品凡多，未能尽录，欢迎来电查询。

北京分公司：北京海淀区知春路 132 号中发电子大厦 3097 号

TEL: 010-81159046 82615020 13501189838 FAX: 010-62543996

上海分公司：上海市北京东路 668 号上海赛格电子市场 D125 号

TEL: 021-28311762 56703037 13701955389 FAX: 021-56703037

西安分公司：西安高新开发区 20 所(中国电子科技集团导航技术研究所)

西安劳动南路 88 号电子商城二楼 D23 号

TEL: 029-81022619 13072977981 FAX:029-88789382